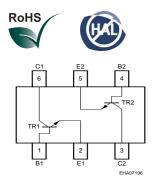


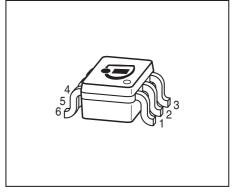
### Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain broadband amplifiers at collector currents from 2 mA to 30 mA
- $f_{\rm T}$  = 8 GHz,  $NF_{\rm min}$  = 0.9 dB at 900 MHz
- Two (galvanic) internal isolated Transistor in one package
- For orientation in reel see package information below
- Pb-free (RoHS compliant) and halogen-free package with visible leads
- Qualification report according to AEC-Q101 available



ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration						Package
BFS483	RHs	1=B	2=E	3=C	4=B	5=E	6=C	SOT363



## BFS483



Parameter	Symbol	Value	Unit
Collector-emitter voltage	V <sub>CEO</sub>	12	V
Collector-emitter voltage	V <sub>CES</sub>	20	
Collector-base voltage	V <sub>CBO</sub>	20	
Emitter-base voltage	V <sub>EBO</sub>	2	
Collector current	I <sub>C</sub>	65	mA
Base current	I <sub>B</sub>	5	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	450	mW
<i>T</i> <sub>S</sub> ≤ 40 °C			
Junction temperature	TJ	150	°C
Ambient temperature	T <sub>A</sub>	-65 150	
Storage temperature	T <sub>Stg</sub>	-65 150	

#### **Maximum Ratings** at $T_A = 25$ °C, unless otherwise specified

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	245	K/W

**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	12	-	-	V
<i>I</i> <sub>C</sub> = 1 mA, <i>I</i> <sub>B</sub> = 0					
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μA
$V_{\rm CE}$ = 20 V, $V_{\rm BE}$ = 0					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB}$ = 10 V, $I_{\rm E}$ = 0					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	1	μA
$V_{\rm EB}$ = 1 V, $I_{\rm C}$ = 0					
DC current gain	h <sub>FE</sub>	70	100	140	-
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, pulse measured					

 ${}^{1}\mathcal{T}_{S}$  is measured on the collector lead at the soldering point to the pcb

<sup>2</sup>For the definition of  $R_{\text{thJS}}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



Parameter	Symbol		Values	1	Unit
		min.	typ.	max.	
AC Characteristics (verified by random samplin	g)		1	1	
Transition frequency	f <sub>T</sub>	6	8	-	GHz
<i>I</i> <sub>C</sub> = 25 mA, <i>V</i> <sub>CE</sub> = 8 V, <i>f</i> = 500 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.34	0.54	pF
$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.13	-	
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	C <sub>eb</sub>	-	1.1	-	
$V_{\rm EB}$ = 0.5 V, f = 1 MHz, $V_{\rm CB}$ = 0 ,					
collector grounded					
Minimum noise figure	NF <sub>min</sub>				dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
<i>f</i> = 900 MHz		-	0.9	-	
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
<i>f</i> = 1.8 GHz		-	1.4	-	
Power gain, maximum stable <sup>1)</sup>	G <sub>ms</sub>	-	19	-	dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,					
<i>f</i> = 900 MHz					
Power gain, maximum available <sup>2)</sup>	G <sub>ma</sub>	-	12.5	-	dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,	-				
<i>f</i> = 1.8 GHz					
Transducer gain	S <sub>21e</sub>   <sup>2</sup>				dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω,	-				
<i>f</i> = 900 MHz		-	15.5	-	
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
<i>f</i> = 1.8 MHz		-	10	-	

## **Electrical Characteristics** at $T_A$ = 25 °C, unless otherwise specified

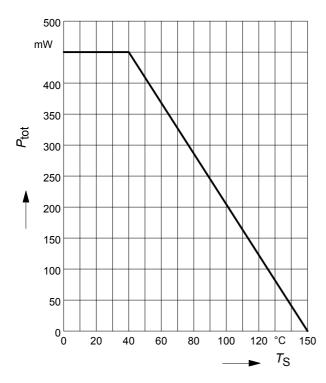
 ${}^{1}G_{\rm ms} = |S_{21} / S_{12}|$  ${}^{2}G_{\rm ma} = |S_{21e} / S_{12e}| \ (k - (k^2 - 1)^{1/2})$ 



**BFS483** 

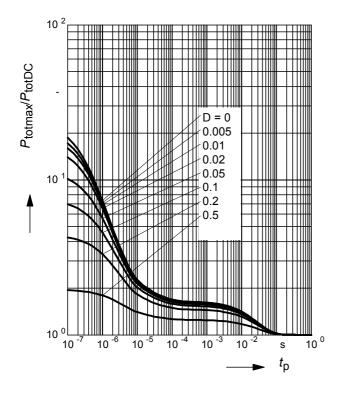
## Total power dissipation $P_{tot} = f(T_S)$

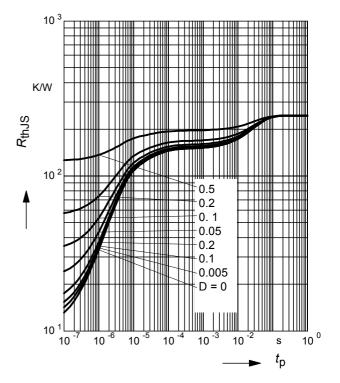
**Permissible Pulse Load**  $R_{\text{thJS}} = f(t_p)$ 



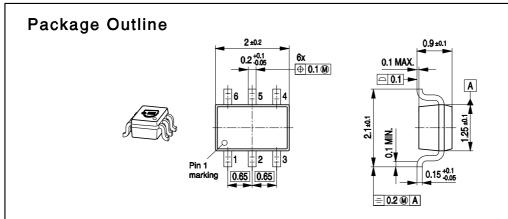
## Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$ 

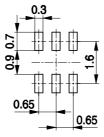






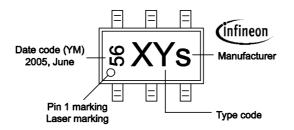


### **Foot Print**



## Marking Layout (Example)

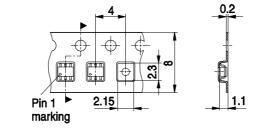
Small variations in positioning of Date code, Type code and Manufacture are possible.



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.







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